

BRCS030N04RA

Rev.A May.-2023

/ Descriptions

TO-220 N
N-CHANNEL MOSFET in a TO-220 Plastic Package.

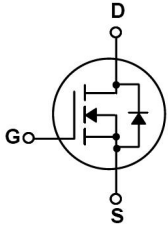
/ Features

$V_{DS}=40V$ $I_D=177A$ $V_{GS}=\pm 20V$
 $R_{DS(on)}@10V$ 3.0m (Type.2.5m)
 $R_{DS(on)}@4.5V$ 5.0m (Type.3.5m)
HF Product.

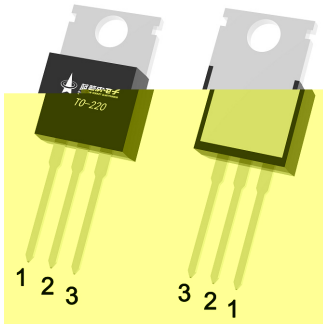
/ Applications

DC/DC
DC Motor Driver, Synchronous Rectification in DC/DC Converters.

/ Equivalent Circuit



/ Pinning



PIN1 G PIN 2 4 D PIN 3 S

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DSS}	40	V
Drain Current	I _D (Tc=25)	177	A
Pulsed Drain Current	I _{DM}	560	A
Gate-Source Voltage	V _{GS}	±20	V
Single Pulsed Avalanche Energy L=0.5mH	E _{AS}	435	mJ
Avalanche Current	I _{AS}	33	A
Total Power Dissipation	P _D (Tc=25)	170	W
Junction and Storage Temperature Range	T _J ,T _{STG}	-55 to 150	
Thermal Resistance-Junction to Ambient	t 10s	R _{JA}	15
	Steady-State		60
Thermal Resistance-Junction to Case	Steady-State	R _{JC}	0.74

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250 A	40	47		V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V V _{GS} =0V			1	A
Gate-Body Leakage Current Forward	I _{GSS}	V _{GS} =±20V V _{DS} =0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} I _D =250 A	1	1.7	3	V
Static Drain-Source On-Resistance	R _{Ds(on)}	V _{GS} =10V I _D =20A		2.5	3	m
		V _{GS} =4.5V I _D =10A		3.5	5	
Forward On Voltage	V _{SD}	V _{GS} =0V I _S =1A			1.2	V
Gate resistance	R _g	V _{GS} =0V V _{DS} =0V, f=1MHz		1.3		
Input Capacitance	C _{iss}	V _{DS} =25V V _{GS} =0V f=1MHz		9600		pF
Output Capacitance	C _{oss}			740		
Reverse Transfer Capacitance	C _{rss}			650		
Total Gate Charge	Q _{g(10V)}	V _{GS} =10V, I _D =20A V _{DS} =20V,		51		nC
Total Gate Charge	Q _{g(4.5V)}			23		
Gate Source Charge	Q _{gs}			13.2		
Gate Drain Charge	Q _{gd}			3.1		

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $R_L=1$ $R_{GEN}=3$		11		ns
Turn-On Rise Time	t_r			11		
Turn-Off Delay Time	$t_{d(off)}$			40		
Turn-Off Fall Time	t_f			10		

/ Electrical Characteristic Curve

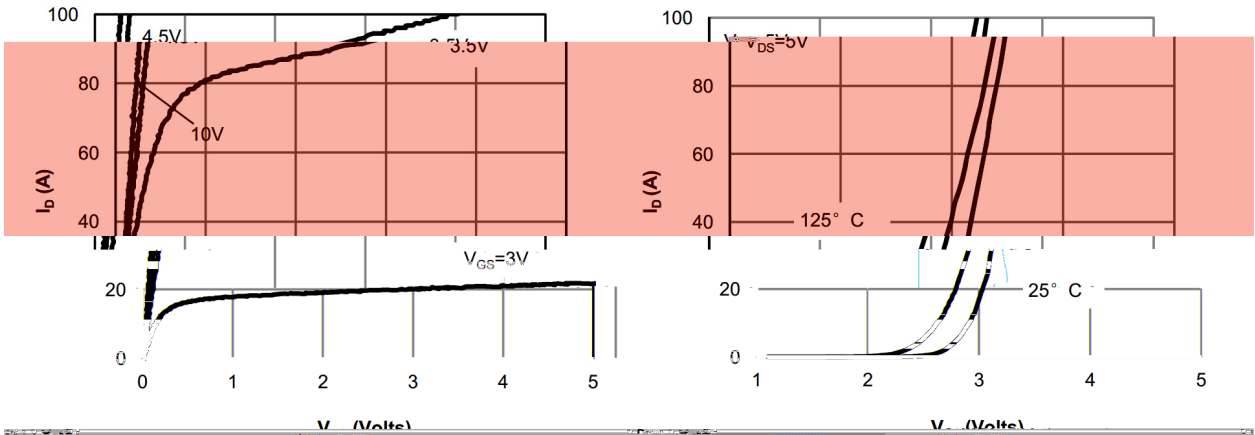


Figure 2: Transfer Characteristics

Figure 1: On-Region Characteristics

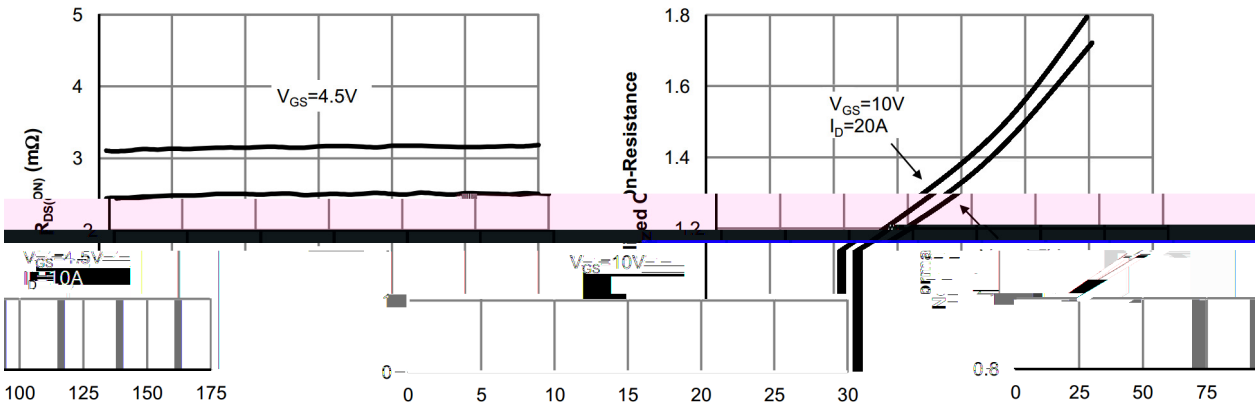


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

Figure 4: On-Resistance vs. Temperature

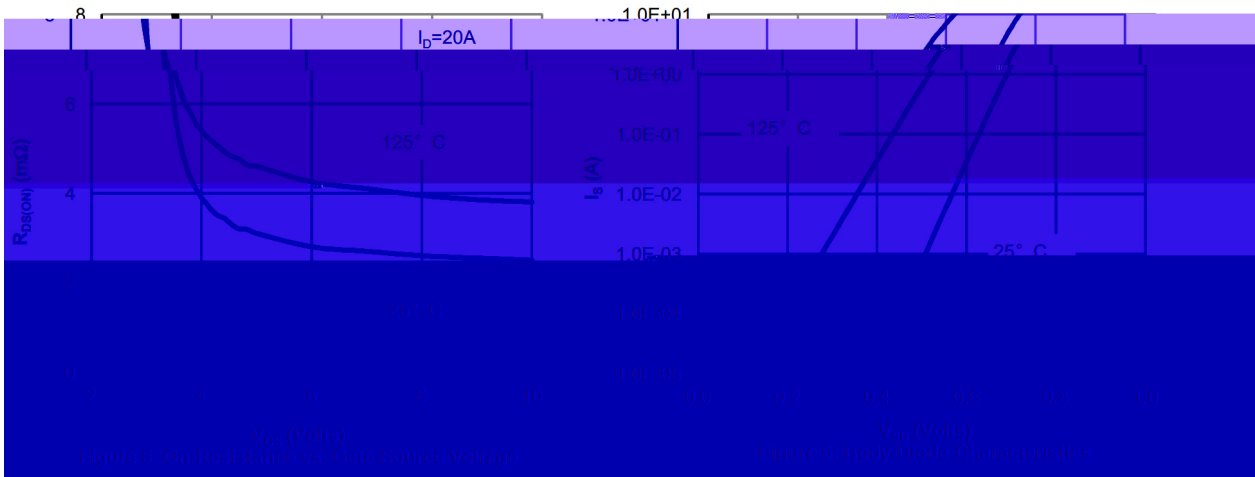


Figure 5: On-Resistance vs. Gate-Source Voltage

Figure 6: On-Resistance vs. Drain Current

/ Electrical Characteristic Curve

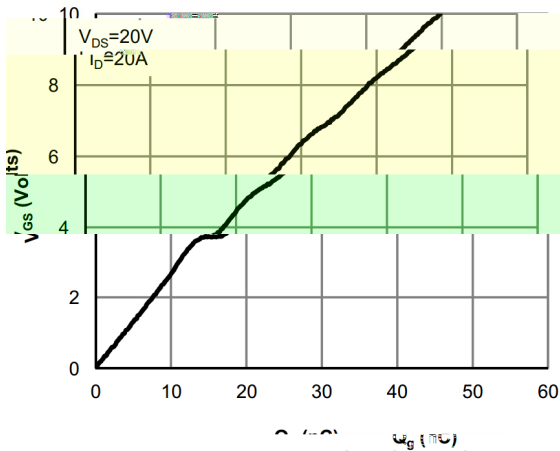


Figure 7: Gate-Charge Characteristics

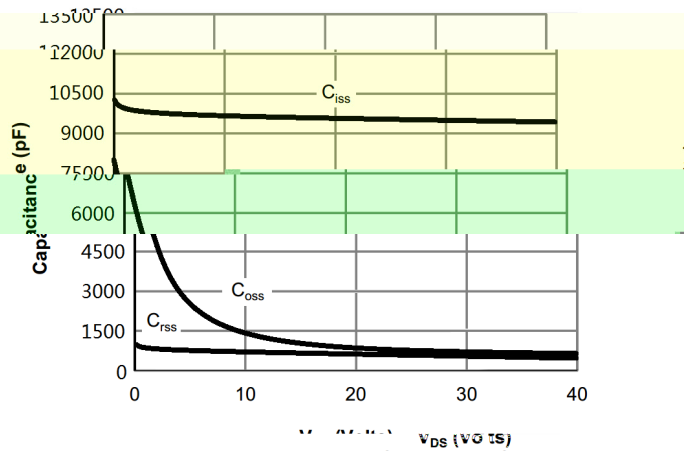


Figure 8: Capacitance Characteristics

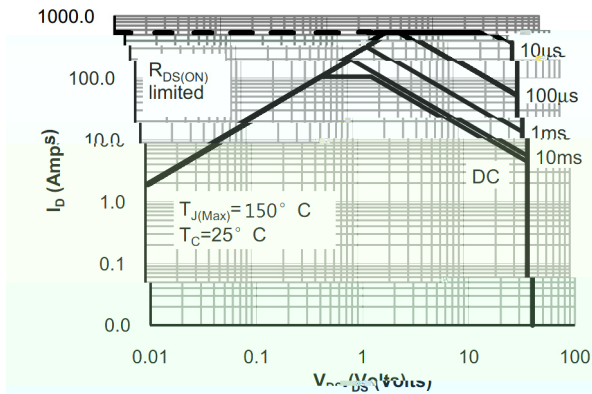


Figure 9: Maximum Forward Biased Safe Operating Area

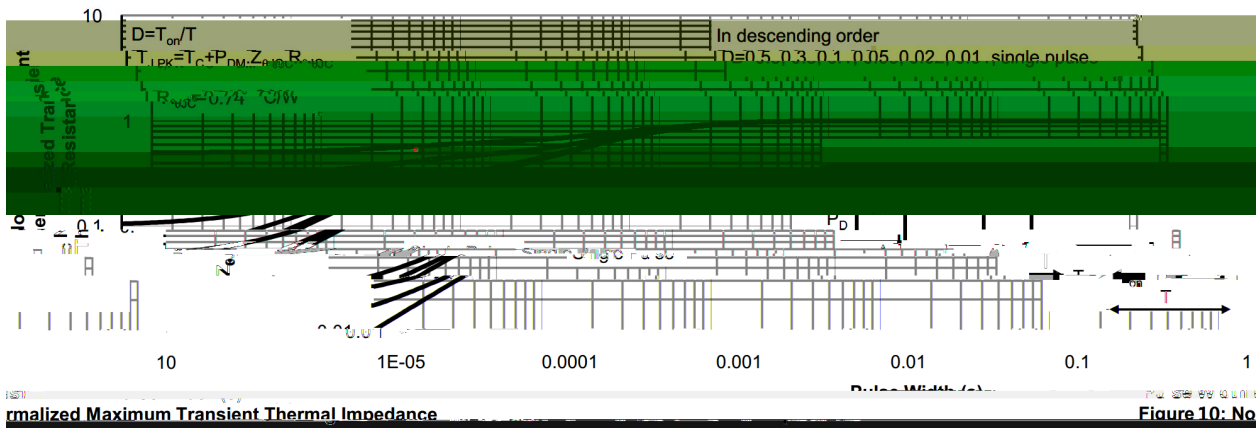
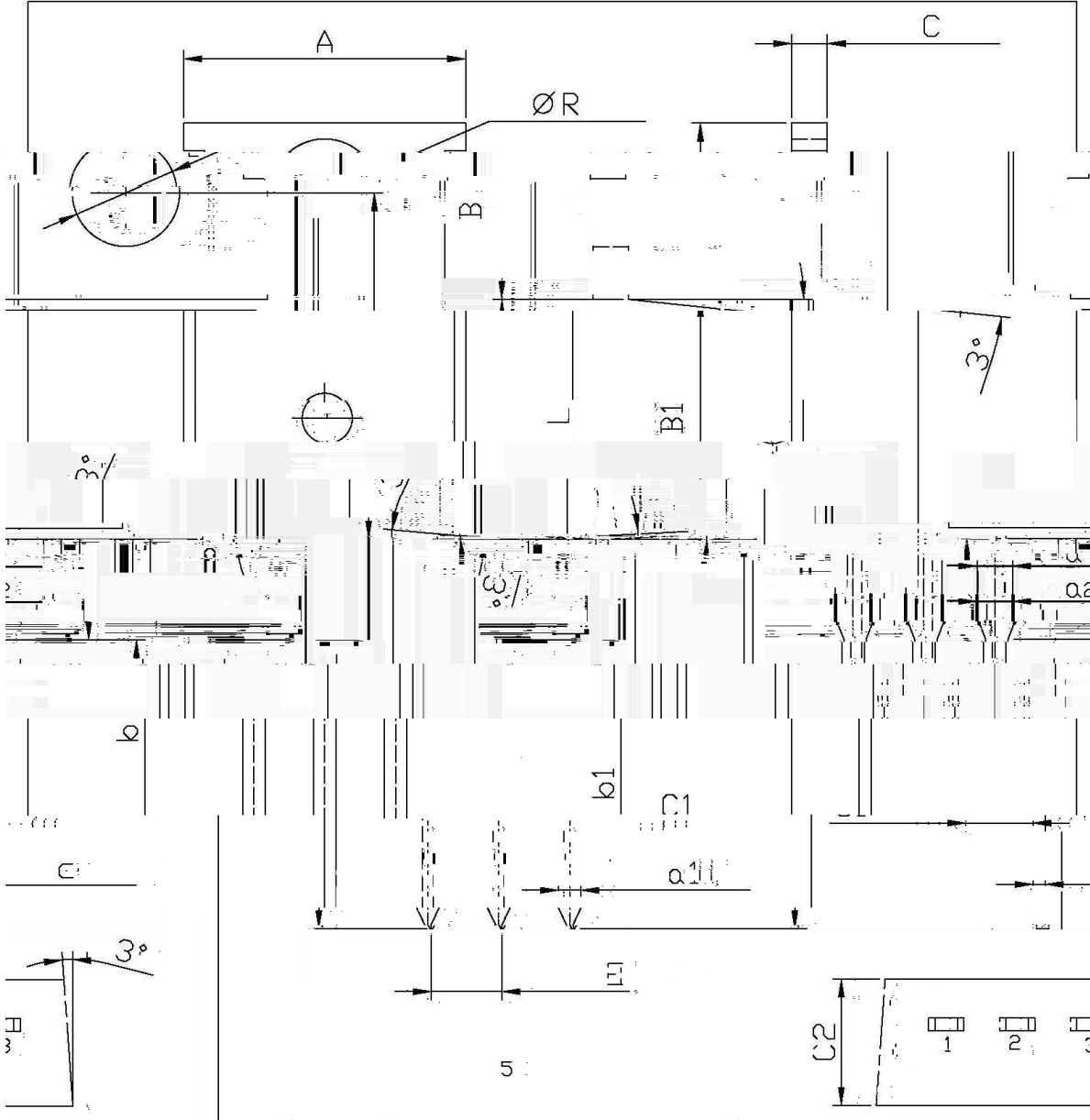


Figure 10: No

/ Package Dimensions

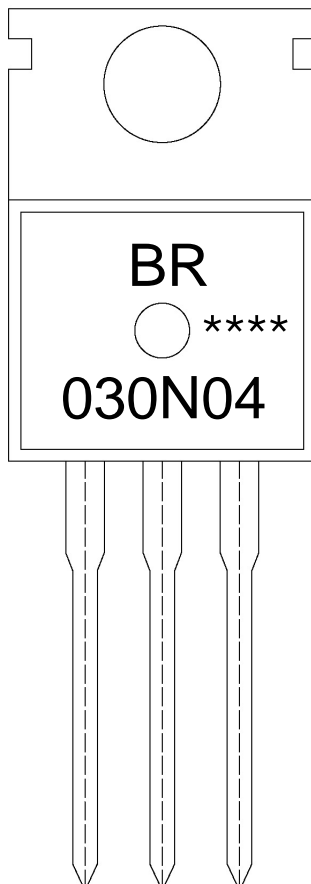
TO-220

单位: mm



Dimensions In Millimeters			Dimensions In Millimeters		
Symbol	Min	Max	Symbol	Min	Max
A	9.8	10.2	C	12	14
R	3.56	3.64	B	6.3	6.7
L	15.7	16.1	B1	9.0	9.4
b	12.6	13.6	C1	2.2	2.6

/ Marking Instructions



BR

030N04

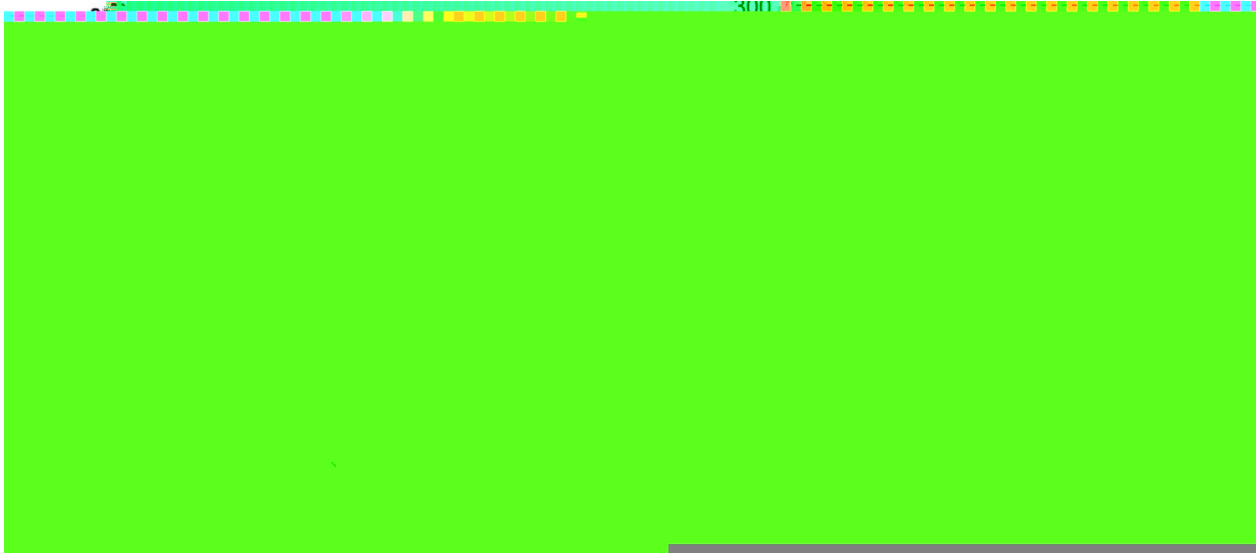
Note:

BR: Company Code

030N04: Product Type

****: Lot No. Code, code change with Lot No

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5sec; | | 2.Peak Temp.:255±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type	Units					Dimension (unit mm ³)		
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag /	Dimension /	Outer Box /
TO-220/F	200	10	2,000	5	10,000	135×190	237×172×102	560×245×195